Boron nitride substrates for high-quality graphene electronic

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#	Paper	IF	Citations
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2299	Ultraconfined Plasmonic Hotspots Inside Graphene Nanobubbles.		
2298	Photocharge Trapping in Two-Sheet Reduced Graphene OxideTi0.87O2 Heterostructures and Their Photoreduction and Photomemory Applications.		
2297	Chemical Interaction-Guided, Metal-Free Growth of Large-Area Hexagonal Boron Nitride on Silicon-Based Substrates.		
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